

BD787 - NPN, BD788 - PNP

Complementary Plastic Silicon Power Transistors

These devices are designed for lower power audio amplifier and low current, high-speed switching applications.

Features

- Low Collector-Emitter Sustaining Voltage – $V_{CEO(sus)}$ 60 Vdc (Min)
- High Current-Gain – Bandwidth Product –
 $f_T = 50$ MHz (Min) @ $I_C = 100$ mAdc
- Collector-Emitter Saturation Voltage Specified at 0.5, 1.0, 2.0 and 4.0 Adc
- Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	60	Vdc
Collector-Base Voltage	V_{CBO}	80	Vdc
Emitter Base Voltage	V_{EBO}	6.0	Vdc
Collector Current – Continuous – Peak	I_C	4.0 8.0	Adc
Base Current – Continuous	I_B	1.0	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	15 0.12	W mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	8.34	$^\circ\text{C/W}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

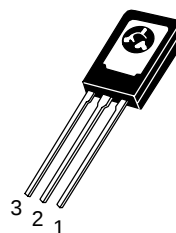
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



ON Semiconductor®

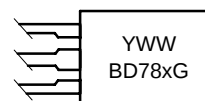
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**4 AMPERES
POWER TRANSISTORS
COMPLEMENTARY SILICON
60 VOLTS, 15 WATTS**



TO-225
CASE 77
STYLE 1

MARKING DIAGRAM



Y = Year
WW = Work Week
BD78x = Device Code
x = 7 or 8
G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping
BD787	TO-225	500 Units/Box
BD787G	TO-225 (Pb-Free)	500 Units/Box
BD788	TO-225	500 Units/Box
BD788G	TO-225 (Pb-Free)	500 Units/Box

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ELECTRICAL CHARACTERISTICS* (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Sustaining Voltage (Note 1) (I _C = 10 mAdc, I _B = 0)	V _{CEO(sus)}	60	–	Vdc
Collector Cutoff Current (V _{CE} = 20 Vdc, I _B = 0) (V _{CE} = 30 Vdc, I _B = 0)	I _{CEO}	–	100	μAdc
Collector Cutoff Current (V _{CE} = 80 Vdc, V _{BE(off)} = 1.5 Vdc) (V _{CE} = 40 Vdc, V _{BE(off)} = 1.5 Vdc, T _C = 125°C)	I _{CEX}	– –	1.0 0.1	μAdc mAdc
Emitter Cutoff Current (V _{EB} = 6.0 Vdc, I _C = 0)	I _{EBO}	–	1.0	μAdc
ON CHARACTERISTICS (Note 1)				
DC Current Gain (I _C = 200 mAdc, V _{CE} = 3.0 Vdc) (I _C = 1.0 Adc, V _{CE} = 3.0 Vdc) (I _C = 2.0 Adc, V _{CE} = 3.0 Vdc) (I _C = 4.0 Adc, V _{CE} = 3.0 Vdc)	h _{FE}	40 25 20 5.0	250 – – –	–
Collector–Emitter Saturation Voltage (I _C = 500 mAdc, I _B = 50 mAdc) (I _C = 1.0 Adc, I _B = 100 mAdc) (I _C = 2.0 Adc, I _B = 200 mAdc) (I _C = 4.0 Adc, I _B = 800 mAdc)	V _{CE(sat)}	– – – –	0.4 0.6 0.8 2.5	Vdc
Base–Emitter Saturation Voltage (I _C = 2.0 Adc, I _B = 200 mAdc)	V _{BE(sat)}	–	2.0	Vdc
Base–Emitter On Voltage (I _C = 2.0 Adc, V _{CE} = 3.0 Vdc)	V _{BE(on)}	–	1.8	Vdc
DYNAMIC CHARACTERISTICS				
Current–Gain – Bandwidth Product (I _C = 100 mAdc, V _{CE} = 10 Vdc, f = 10 MHz)	f _T	50	–	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _C = 0) (f = 0.1 MHz)	C _{ob}	– –	50 70	pF
Small–Signal Current Gain (I _C = 200 mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz)	h _{fe}	10	–	–

*Indicates JEDEC Registered Data

1. Pulse Test; Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

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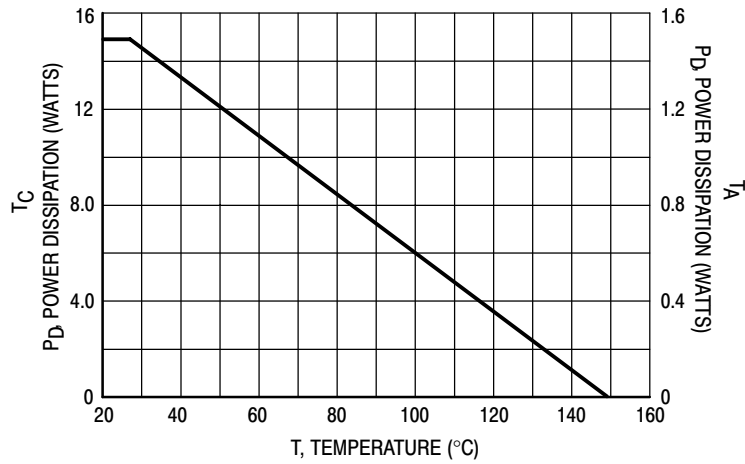


Figure 1. Power Derating

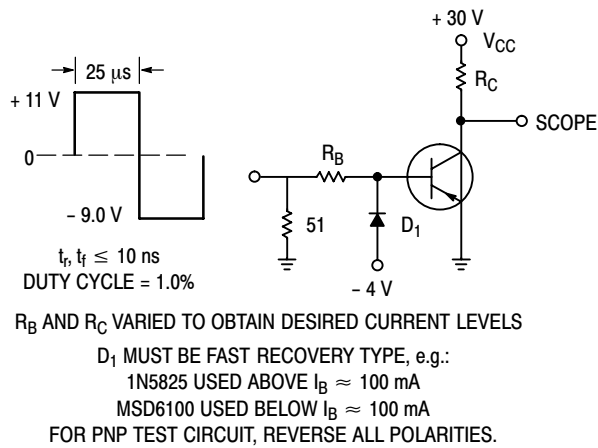


Figure 2. Switching Time Test Circuit

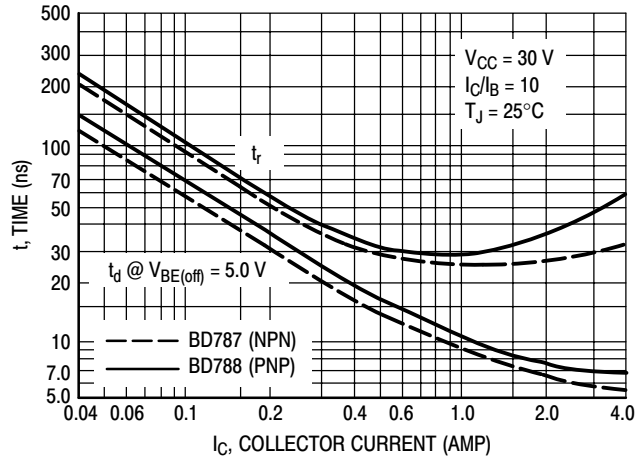


Figure 3. Turn-On Time

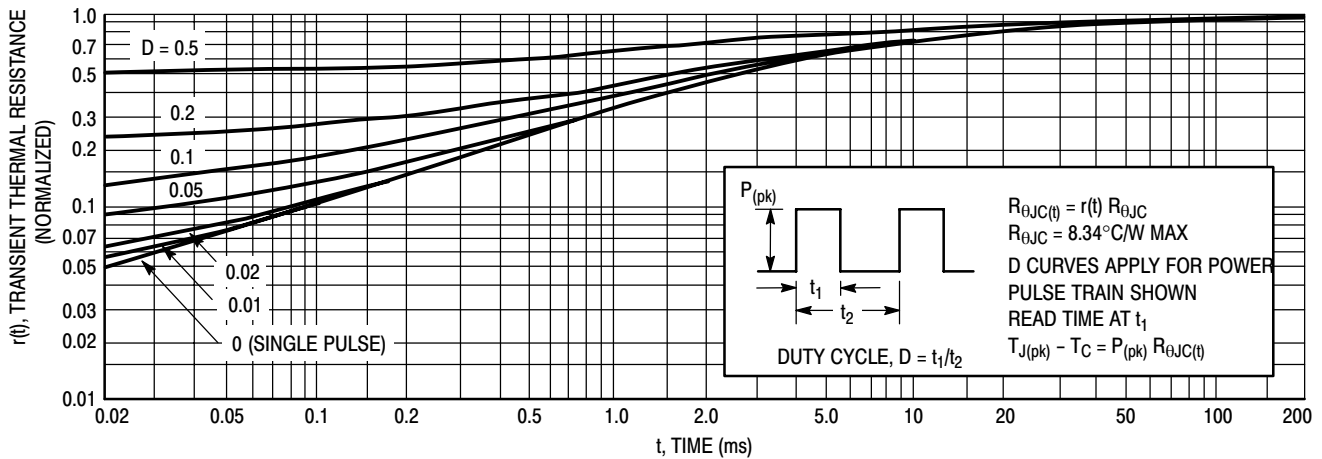


Figure 4. Thermal Response

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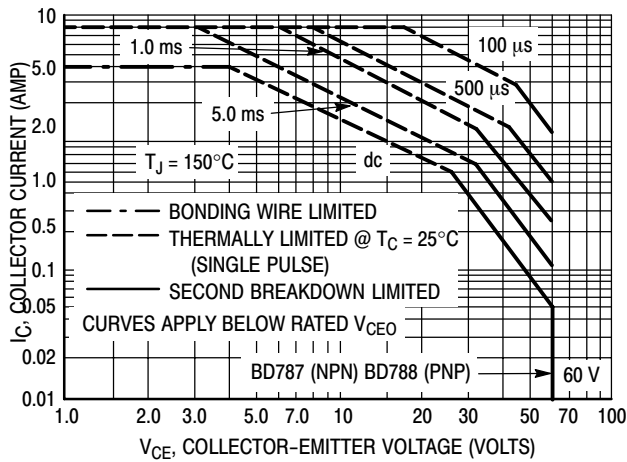


Figure 5. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation, i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on $T_{J(pk)} = 150^\circ\text{C}$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^\circ\text{C}$, $T_{J(pk)}$ may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

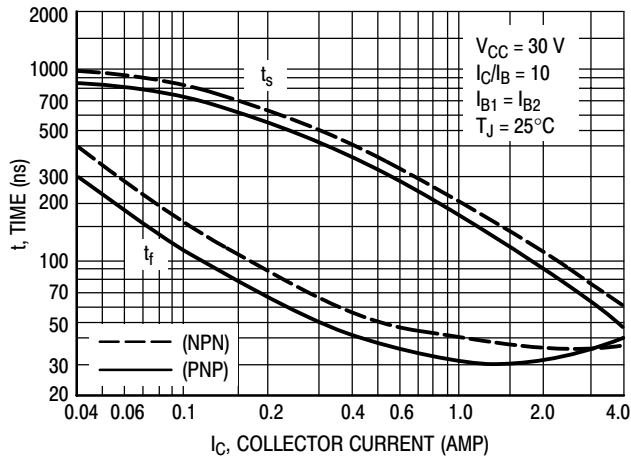


Figure 6. Turn-Off Time

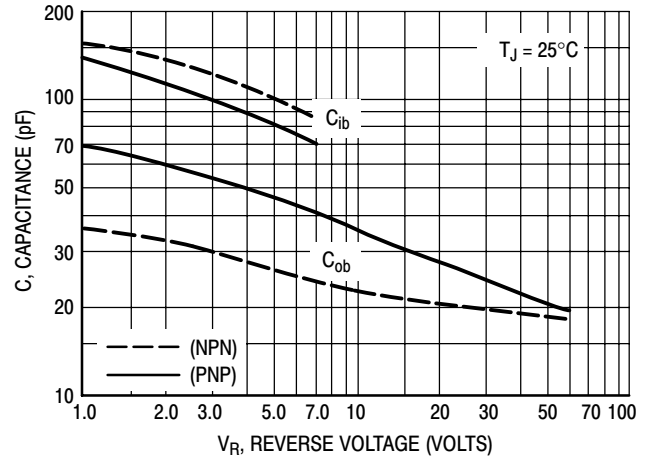


Figure 7. Capacitance

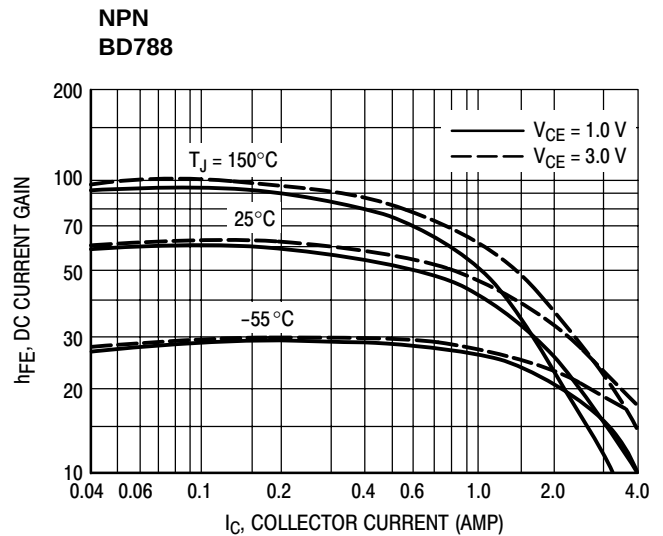
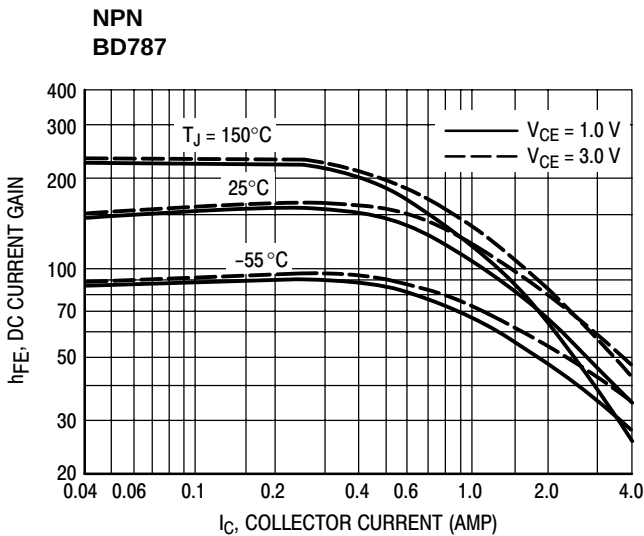


Figure 8. DC Current Gain

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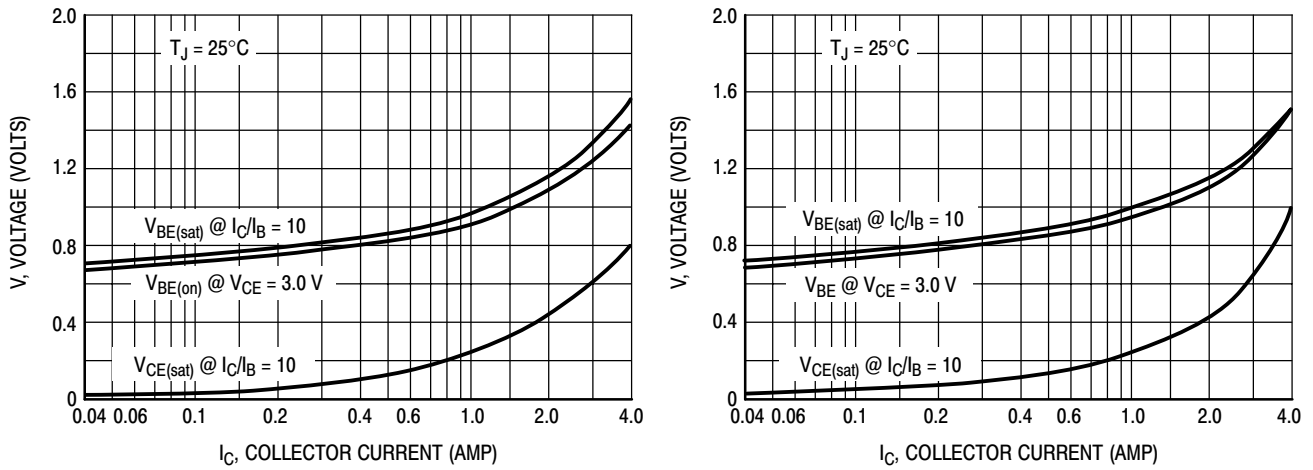


Figure 9. "On" Voltages

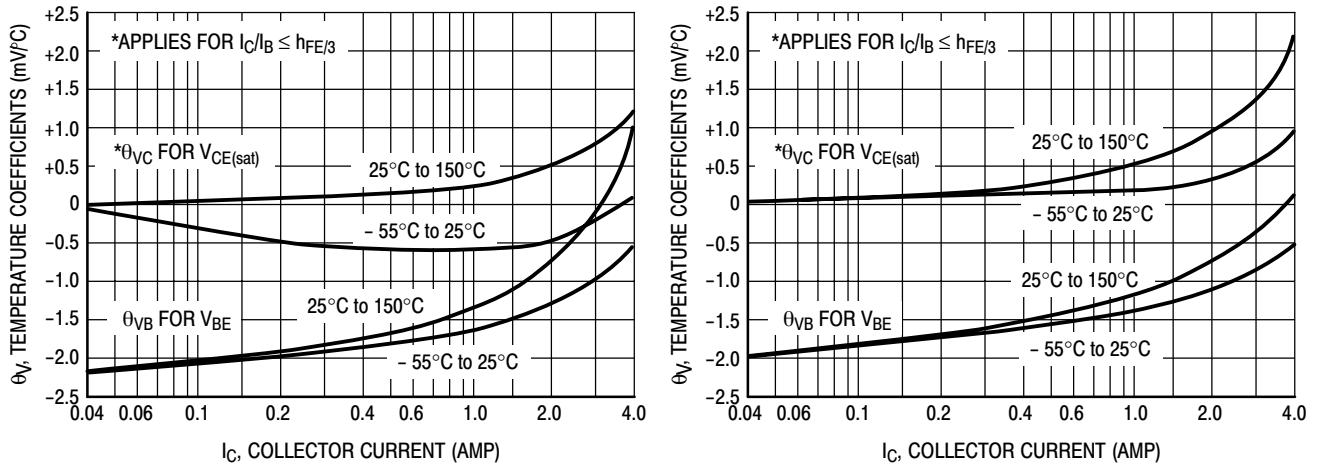
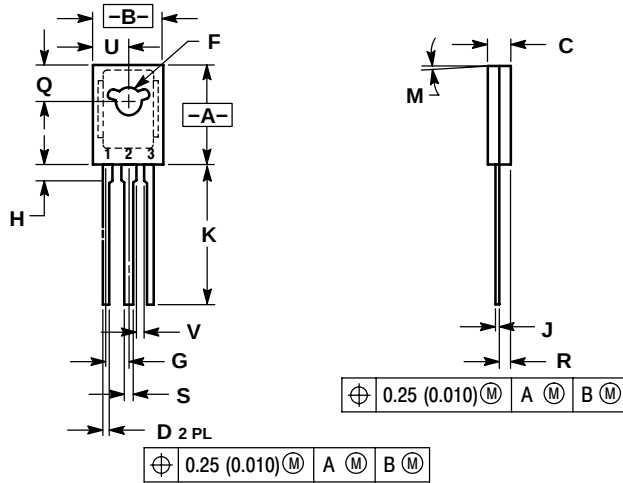


Figure 10. Temperature Coefficients

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PACKAGE DIMENSIONS

TO-225
CASE 77-09
ISSUE Z



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 077-01 THRU -08 OBSOLETE, NEW STANDARD 077-09.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.425	0.435	10.80	11.04
B	0.295	0.305	7.50	7.74
C	0.095	0.105	2.42	2.66
D	0.020	0.026	0.51	0.66
F	0.115	0.130	2.93	3.30
G	0.094 BSC		2.39 BSC	
H	0.050	0.095	1.27	2.41
J	0.015	0.025	0.39	0.63
K	0.575	0.655	14.61	16.63
M	5° TYP		5° TYP	
Q	0.148	0.158	3.76	4.01
R	0.045	0.065	1.15	1.65
S	0.025	0.035	0.64	0.88
U	0.145	0.155	3.69	3.93
V	0.040	---	1.02	---

STYLE 1:

1. EMITTER
2. COLLECTOR
3. BASE

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